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## What is claimed:

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A driver circuit comprising a semiconductor integrated circuit having a 1. transistor in which a drive signal is applied to the transistor to drive the transistor to thereby drive a load, the driver circuit comprising:

a signal line that supplies the drive signal, the signal line-being separated from the transistor by a dielectric layer; and

at least two connection sections that connect the signal line to a gate electrode of the transistor, the connection sections being provided in a width direction of the gate electrode.

A driver circuit comprising a semiconductor integrated circuit having a 2. plurality of transistors in which a single drive signal is applied to each of the transistors to drive the transistors to thereby drive a load, the driver circuit comprising:

a signal line that supplies the drive signal, the signal line being separated from each of the transistors by a dielectric layer; and

at least two connection sections that connect the signal line to a gate electrode of at least one of the transistors, the connection sections being provided in a width direction of the gate electrode.

- A driver circuit according to claim 2, wherein the at least two connection 3. 1 sections includes two or more connection sections provided for each of the transistors. 2
- A driver circuit according to claim 2, wherein the at least two connection 1 sections includes two or more connection sections provided for each of the transistors except 2 one of the transistors. 3

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1	5.	A driver circuit according to claim 2, wherein at least two of the plurality of
transistors have a different number of connection sections.		

- 1 6. A driver circuit according to claim 3, wherein at least two of the plurality of transistors have a different number of connection sections.
- 7. A driver circuit according to claim 4, wherein at least two of the plurality of transistors have a different number of connection sections.
  - 8. A driver circuit according to claim 2, wherein the plurality of transistors have different numbers of connection sections.
  - 9. A driver circuit comprising a semiconductor integrated circuit having a plurality of transistors in which a single drive signal is applied to each of the transistors to drive the transistors to thereby drive a load, the driver circuit comprising:

a signal line that supplies the drive signal, the signal line being separated from each of the transistors by a dielectric layer; and

connection sections for connecting the signal line to a gate electrode of each of the transistors, the connection sections being provided in a width direction of the gate electrode, wherein at least two of the plurality of transistors have a different number of connection sections.

10. A driver circuit according to claim 9, wherein the plurality of transistors have different numbers of connection sections.



